INDUSTRIAL MEMORY SOLUTIONS

NAND FLASH PRODUCTS & DRAM MODULES



In more detail Swissbit offers to it's customers the following areas of service:

PRODUCT DEPTH

- Complete line of DRAM modules and NAND Flash Solid State Drives available in a variety of interfaces and form factors
- Both leading edge technology and legacy product offerings
- Extended and industrial temperature grade products
- Unique Chip-On-Board (COB) technology
- Small form factor removable NAND Flash cards
- Memory In Package Solutions

SALES SERVICE AND ENGINEERING SUPPORT

- Fast, effective and experienced sales staff on hand to serve your needs
- Our expert technical staff is available for quick response
- Joint product qualification service
- In-House manufacturing in Germany
- Worlds only COB DRAM memory module manufacturer

CUSTOMIZATION

- Custom DRAM module and FLASH designs
- Security features
- Individual labeling
- Design In support

OEM SERVICES

- Controlled Bill of Materials (BOM)
- Serialization and Lot Code Tracking
- Support of long life cycles
- Stringent PCN and ECN process

TEST FOR RELIABILITY

- Advantest, King Tiger Technology and Tanisys Technology test equipment
- World class application testing
- System Level Test During Burn-In (TDBI)
- Extended and industrial temperature testing
- Environmental testing

COMPLIANCE TO

- JEDEC, SDA, CFA, USB-IF, SATA-IO
- RoHS, REACH, WEEE
- UL
- FCC, CE

QUALITY STANDARD

- ISO 9001:2008

ASSOCIATIONS

- Member of CompactFlash Association (CFA)
- Member of SATA-10
- Member of USB
- Implementers Forum
- Member of SecureDigital Association (SDA)
- Member of Memory Implementers Forum
- Member of JEDEC
- Member of Small Form Factor Special Interest Group SFF-SIG





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DRAM MODULES

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Mini RDIMM
SORDIMM



TECHNOLOGY

COB	C
Technology Capabilities	1

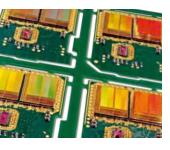
PART NUMBERS

NAND Flash Part Numbers 22 DRAM Module Part Numbers 23



WHY CHOOSE SWISSBIT







Swissbit, the largest independent industrial DRAM module and FLASH storage product manufacturer in Europe, was created through a management buy-out from Siemens Memory Products in 2001. With over 20 years of experience in the memory industry Swissbit has become a world class leader in technology supplying high quality, high reliability memory storage solutions in all of the established DRAM and Flash interfaces. Swissbit's primary focus is on the demanding applications in the industrial Computer markets including Embedded Computing, Automation, Measurement, Communication, Network, Military, Aerospace, Transportation, Casino Gaming and Medical Equipment. Swissbit customers can rely on longterm availability due to a dedicated controlled Bill of Material (BOM) process that results in products with long lifecycles, reliability, endurance and longevity, even when running 24 hour / 7 day service cycles. Swissbit products feature exceptional resistance to shock and vibration and are available in commercial, extended and industrial temperature grades along with Conformal Coating if required.

High Quality products "Made in Germany" and designed with Swiss Precision result in outstanding industrial memory solutions. Swissbit develops all of its products in Switzerland with manufacturing and test facilities utilizing state-of-the-art equipment, processes and production methods which are based in Germany. Swissbit uses the latest technology and techniques in order to offer optimal products for all customer needs, such as System in Package (SiP), Flip-Chip and SMT technology. As the world's only manufacturer, Swissbit utilizes the Chip-On-Board (COB) technology to produce a line of very robust and highly integrated DRAM memory modules.

Swissbit carefully selects premium materials and subassemblies, conducts rigorous quality inspections and utilizes internal and external test laboratories and simulation systems along with extensive certified ISO 9001:2008 quality management processes to ensure innovative memory solutions that meet even the highest demands of today and into tomorrow. To guarantee competitive pricing, Swissbit focuses on lean company structures, efficient processes and long-term relationships with all major semiconductor manufacturers. Because applications differ. Swissbit also offers extensive customer service and will individually tailor memory solutions to meet specific requirements of system manufacturers and integrators regarding performance and cost.





WIDE TEMPERATURE SUPPORT

The storage solutions from Swissbit are designed and approved to operate reliably over a wide temperature range. The products are verified at temperature corners and pre-stressed with a burn-in operating functional test (Test During Burn-In – TDBI).



ESD AND EMI SAFE

The product designs are in-line with the latest regulations for electrostatic discharge and electromagnetic interference. Swissbit aims to exceed these limits with their own in house technology and production capabilities, for example with System in Package (SiP) competence.



SHOCK AND VIBRATION

Robustness is one of our key specification targets. The design, assembly and selected materials guarantee an extremely solid design which has been validated by intense testing.



LIFE TIME MONITORING (LTM)

The Swissbit LifeTimeMonitoring (SBLTM) feature enables users to access the device's detailed life time status and allows predicting imminent failure and thus avoiding unexpected data loss. This feature uses an extended S.M.A.R.T. (Self-Monitoring, Analysis and Reporting Technology) interface or vendor specific commands to retrieve the Flash product information.

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5				2

ZONE PROTECTION

The device allows configuring multiple zones with either no protection, write protection or access protected settings. Each zone is secured with a separate password. A Windows tool or a programming library is available, the latter allowing easy integration of the SBZoneProtection functionality into customer applications.



FAST ERASE

This feature uses an uninterruptable sequence of single block erase commands for fastest possible destruction of user data. Even a power-off cannot stop the process which will continue after power restoration.

CONFORMAL COATING

For selected products Swissbit offers a special protective coating with a thin polyurethane film against aggressive environmental conditions such as dust, moisture or corrosive gas.

		1			£		••
S-300U	•	•	•	0	0	0	• 1)
S-200U	•	•	•	•	0	0	• 1)
S-200/220	•	•	•	•	0	0	0
M-100	•	•	•	•	0	0	• 1)
C-300	•	•	•	•	0	0	O
C-320	•	•	•	•	٥	٥	O
C-400	•	•	•	•	٥	٥	O
P-120	•	•	•	•	٥	٥	O
X-200	•	•	•	•	0	0	O
X-200M	•	0	•	•	0	0	•
X-2005	•	0	•	•	0	0	O
F-100	•	•	•	•	0	0	O
F-200	•	•	•	•	O	٥	O
miniTWIST II	0	•	•	•	0	0	0
unitedCONTRAST II	•	•	•	•	0	0	0
USB FLASH MODULE U-110	•	0	•	•	0	0	0

default implemented; •¹ inherently protected by molding process; • on request; • not available;





- Optimized Error Correction Code
- Efficient Algorithms for Bad Block Management
- Real Life Time Monitoring
- Sophisticated Wear Leveling & Bad Block Management
- Power Fail Robustness

MMC / MICROSD / SDHC

Swissbit's INDUSTRIAL product lines of SecureDigital (SD) & Multimedia cards are specifically designed, manufactured and tested to withstand extreme environmental conditions. The use of SLC (Single Level Cell) Flash combined with an optimized Flash controller provides a number of enhanced product features such as built-in error correction, bad block management, sophisticated wear leveling & bad block management algorithms, power loss protection and power saving modes. Special attention is dedicated to the mechanical stability and enhanced ESD protection. A high reliability housing with special connector support provides resistance against bending and torque. Furthermore, the gold plated SD connectors will last a minimum of 10,000 insertions.

		4	B		£		•
S-300U	•	•	•	0	0	0	• 1)
S-200U	•	•	•	•	0	0	• 1)
S-200/220	•	•	•	•	0	0	0
M-100	•	•	•	•	0	0	• 1)
default implemented; • ¹ inherently protected by molding process; • on request; O not available;							









	MICROSD	MICROSD	SECURE DIGITAL	MULTIMEDIA CARD	
	(SD / SDHC)		(SD / SDHC)		
Series	S-300µ	S-200µ	S-200/220	M-100	
Interface Compliance	SDA 2.0, SDHC class 6 / 10	SDA 2.0 class 6	SDA 2.0, SDHC class 6 (10)	MMC 3.31, 4.1 & 4.2	
Connector	microSD	microSD	SD	ММС	
Physical Form	15.0 x 11.0 x (0.7) 1 mm	15.0 x 11.0 x (0.7) 1 mm	32.0 x 24.0 x 2.1 mm	32.0 x 24.0 x 1.4 mm	
Flash Type	SLC 2x nm	SLC 4x nm	SLC	SLC	
Density	2 GB - 8 GB	512 MB - 2 GB	512 MB - 8 GB	128 MB	
Operating Temperature	Extended: -25°C to +85°C	Extended: -25°C to +85°C Industrial: -40°C to +85°C	Extended: -25°C to +85°C Industrial: -40°C to +85°C	Extended: -25°C to +90°C Industrial: -40°C to +90°C	
Storage Temperature	-40°C to +85°C	-40°C to +100°C	-40°C to +100°C	-40°C to +100°C	
Shock	50 G	1000 G	1 000 G	1000 G	
Vibration	2 G	15 G	15 G	15 G	
Humidity	93 % RH 40°C, 500 hrs	85 % RH 85°C, 1000 hrs	85 % RH 85°C, 1 000 hrs	85 % RH 85°C, 1 000 hrs	
Data Transfer Mode	SD, SPI	SD, SPI	SD, SPI	1 bit MMC, SPI	
Performance	Burst Rate up to 25 MB/s Read Seq. up to 24 MB/s Write Seq. up to 22 MB/s (2 GB - 12 MB/s)	Burst Rate up to 25 MB/s Read Seq. up to 21 MB/s Write Seq. up to 13 MB/s	Burst Rate up to 25 MB/s Read Seq. up to 21 MB/s Write Seq. up to 18 MB/s (512 MB - 13 MB/s)	Burst Rate up to 6.5 MB/s Read Seq. up to 5.7 MB/s Write Seq. up to 5.9 MB/s	
Voltage	2.7 – 3.6 V Normal 2.0 – 3.6 V Basic Communication	2.7 – 3.6 V Normal 2.0 – 3.6 V Basic Communication	2.7 – 3.6 V Normal 2.0 – 3.6 V Basic Communication	2.7 – 3.6 V Normal 2.0 – 3.6 V Basic Communication	
Power Consumption	Read typ 50 mA Write typ 50 mA Sleep max 0.4 mA	RW typ 30 mA Write typ 40 mA Sleep max 0.4 mA	RW typ28 mA (max 60 mA)Write typ55 mA (max 90 mA)Sleep max0.3 mA	31	
Marking	Swissbit, Part Number, Lot Code, Mfg. Date	Swissbit, Part Number, Lot Code, Mfg. Date	Swissbit, Density, CE, Pb free, Part Number, Lot Code, Mfg. Date	Swissbit, Density, CE, Pb free, Part Number, Lot Code, Mfg. Date	
Target Application	Networking, Telecommunication, Enterprise Computing, Measure- ment, Point-of-Sale, etc.	Industrial Embedded Sys	stems, Medical Solutions, Point-c Automation Solutions, etc.	of-Sale, Gaming Industry,	
Tools	-	Life Tin	ne Monitoring with SD / SPI comm	and set	
Part Number	SFSDxxxxNvBWxss-t-dd-1r1-STD	SFSDxxxxNxBNxss-t-dd-1r1-STD	SFSDxxxxLvBNxss-t-dd-1r1-STD	SFMMxxxxOvBNxss-t-dd-1r1-STD	
	 Compliant with SDA2.0 Specification Advanced Wear Leveling & Block Management Power Fail Protection 	 Compliant with SDA2.0 Specification Sophisticated Wear Leveling & Bad Block Management Life Time Monitoring over extended command set Intelligent Power Fail Protection & Recovery Life Time Moniextended command set Sophisticated Bad Block M Life Time Moniextended command set Recovery Life Time Moniextended command set Sophisticated Bad Block M Life Time Moniextended command set Sophisticated Bad Block M Life Time Moniextended command set Sophisticated R Bad Block M Life Time Moniextended command set Intelligent Power 			





CompactFlash[™] (CF) cards are still the most popular Flash-based storage solution used in the embedded and industrial markets. The form factor as well as the connector is well established. With strong focus on quality, reliability, robustness and longevity, Swissbit designs its cards with no compromise.

We only select components and apply design rules which fit the stringent requirements of our industrial customers. Our hardware and firmware has been tested and qualified by our experienced team and proved in many challenging customer applications.

Swissbit's CF Series C-3x0 and C-4x0 come in both, commercial (o°C to 70°C) and industrial temperature (-40°C to 85°C) ranges, providing rugged and reliable memory for a wide range of demanding applications. They are designed to solve a broad spectrum of concerns from compatibility, booting and power fail safety issues to long-term supply, controlled BOM and outstanding Flash protocol handling techniques to ensure industry leading data integrity. In contrast to commonly promoted sequential performance values, Swissbit is especially focusing on optimized random access values, being one of the key factors in industrial applications.

	C-300	C-320	C-400	P-120
Power Fail Protection	•	•	•	•
Power Fail Recovery	•	•	•	•
SLC NAND Flash	•	•	•	•
Controlled BOM / PCN Process	•	•	•	•
Standard S.M.A.R.T. Support	O	•	•	•
Security Erase / Security Feature Set	0	O	O	٥
Read Disturb Management	0	O	•	٥
Trim support	0	0	•	0

FEATURE COMPARISON

default implemented;
 on request;
 not available;

		1			£		
C-300	•	•	•	•	0	0	٥
C-320	•	•	•	•	٥	٥	٥
C-400	•	•	•	•	٥	٥	٥
	default implemented: • inherently protected by molding process: • on request: • one available						not available:

	A Swissbit' 128MB Industrial CompactFlashCard	4GB Industrial CompactFlashCard	UDMA6 CF swissbit 64GB Industrial CompactFlashCard
	COMPACTFLASH™ CARD	COMPACTFLASH™ CARD	COMPACTFLASH™ CARD
Series	C-300	C-320	C-400
Interface Compliance	CFA4.1 / CFA3.0 True IDE / PC card	CFA4.1 / CFA3.0 True IDE / PC card	CFA5.0 / CFA4.1 & 3.0 compliant True IDE / PC card
Connector	CFC Type I	CFC Type I	CFC Type I
Physical Form	36.4 x 42.8 x 3.3 mm	36.4 x 42.8 x 3.3 mm	36.4 x 42.8 x 3.3 mm
Flash Type	SLC	SLC	SLC
Density	128 MB to 8 GB	2 GB to 32 GB	2 GB to 64 GB
Operating Temperature	Commercial: o°C to +70°C Industrial: -40°C to +85°C	Commercial: o°C to +70°C Industrial: -40°C to +85°C	Commercial: o°C to +70°C Industrial: -40°C to +85°C
Storage Temperature	-50°C to +100°C	-50°C to +100°C	-50°C to +100°C
Shock	1 500 G	1 500 G	1 500 G
Vibration	20 G	20 G	20 G
Humidity	85 % RH 85°C, 1 000 hrs	85 % RH 85°C, 1 000 hrs	85 % RH 85°C, 1 000 hrs
Data Transfer Mode	Up to UDMA4, MDMA4 & PIO6	Up to UDMA4, MDMA4 & PIO6	Up to UDMA6, MDMA4 & PIO6
Performance	Burst Rate up to 66 MB/s Read Seq. 1ch up to 24 MB/s 2ch up to 37 MB/s Write Seq. 1ch up to 10 MB/s 2ch up to 20 MB/s	Burst Rate up to 66 MB/s Read Seq. up to 45 MB/s Write Seq. up to 35 MB/s (512 MB-13 MB/s)	Burst Rate up to 133 MB/s Read Seq. up to 65 MB/s Write Seq. up to 40 MB/s Write Rand. 4k up to 300 IOPS
Voltage	3.3 V +/- 5 %, 5 V +/- 10 %	3.3 V +/- 5%, 5 V +/- 10%	3.3 V +/- 5 %, 5 V +/- 10 %
Power Consumption	PIO typ 50 mA @ 3.3 V DMA typ 70 mA @ 3.3 V DMA typ 110 mA @ 5 V	PIO typ 60 mA @ 3.3 V DMA typ 90 mA @ 3.3 V DMA typ 130 mA @ 5 V	PIO typ 60 mA @ 3.3 V DMA typ 80 mA @ 3.3 V DMA typ 90 mA @ 5 V
Marking	WEEE, Swis	sbit, Density, CE, Part Number, Lot	Code, RoHS
Target Application	Industrial Embedded Sy	stems, Medical Solutions, Point-of Automation Solutions, etc.	-Sale, Gaming Industry,
Tools		Application, API/DLL for extended S Security & SBZoneProtection option	
Part Number	SFCFxxxxHxBK1ss-t-xx-5r3-SMA 1ch SFCFxxxxHxBKxss-t-xx-5r3-SMA 2ch	SFCFxxxxHxB0xss-t-dd-5r3-SMA	SFCFxxxxHvBUxss-t-dd-5r7-SMA
	 Sophisticated Wear Leveling & S.M.A.R.T. support with extend Intelligent Power Fail Protectio Security Features available C-3; ZoneProtection option, Fast Era 	led command set n & Recovery 20 2 – 16GB:	 Low power consumption High 10PS performance for 4k write (no DRAM) Sophisticated Wear Leveling & Bad Block Management Read Disturb Management Intelligent Power Fail Protection & Recovery S.M.A.R.T. support with extended command set Trim support SBZoneProtection option Fast Erase option





Swissbit's Solid-State Drive (SSD) line are drop-in replacements for traditional 2.5" hard disk drives (HDD). These SSDs are offered in both, Parallel ATA (PATA) and Serial ATA (SATA) interfaces. This line is designed for industrial usage and does not support dedicated optimization techniques commonly used in "Enterprise SSDs". Critical factors like long data retention, no compromise power fail safety and and long product lifecycles are key for our industrial customers. For that reason our SSD line uses the most reliable SLC Flash combined with rugged hardware design and state-of-the-art firmware technologies to provide the best performance in quality, reliability and data integrity. For many applications, especially in the lower and middle densities Swissbit's SSDs are the HDD replacement of choice.

	SLC	MLC	TLC
High Density	D	•	•
Total Cost Per Bit	Ð	•	•
Reliability & Durability	•	O	0
Industrial Temperature	•	O	O
Low Power Consumption	•	O	O
Write Performance	•	O	O
Partial Programming	•	0	0
ECC Requirement	•	0	0
Data Retention	•	0	0
Longevity	•	0	0

NAND FLASH TECHNOLOGY COMPARISION

● best; ● average; ○ worst



10 NAND FLASH PRODUCTS





PATA SSD 2.5" SOLID STATE DRIVE SATA SSD 2.5" SOLID STATE DRIVE

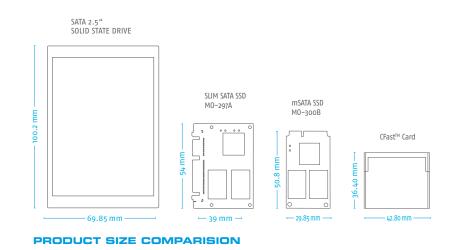
Series	P-120	X-200
Interface Compliance	IDE / ATA 133	SATA II – 3 GBit/s
Connector	ATA 44 pin, 2 mm pitch	15 + 7 pin serial ATA
Physical Form	100.2 x 69.85 x 9.0 mm	100.2 x 69.85 x 9.0 mm
Flash Type	SLC	SLC
Density	4 GB - 32 GB	4 GB - 128 GB
Operating Temperature	Commercial: o°C to +70°C Industrial: -40°C to +85°C	Commercial: o°C to +70°C Industrial: -40°C to +85°C
Storage Temperature	-50°C to +100°C	-50°C to +100°C
Shock	1 500 G	1 500 G
Vibration	20 G	20 G
Humidity	85 % RH 85°C, 1000 hrs	85 % RH 85°C, 1 000 hrs
Data Transfer Mode	up to PIO4, MDMA4, UDMA4	PIO, MDMA, up to UDMA6
Performance	Burst Rateup to 66 MB/sRead Seq.up to 45 MB/sWrite Seq.up to 35 MB/s	Burst Rate up to 300 MB/s Read Seq. up to 120 MB/s Write Seq. up to 95 MB/s
Voltage	5 V +/-10 %	5 V +/- 10 %
Power Consumption	PIO typ 55 mA UDMA typ 135 mA Idle 5 mA	UDMA6 typ 260mA, max 320mA Idle 140mA
Marking	Swissbit, Density, CE, Pb free, Part Number, Lot Code, Mfg. Date, Pin Mode	Swissbit, Density, CE, Pb free, Part Number, Lot Code, Mfg. Date
Target Application	· · · · · · · · · · · · · · · · · · ·	Aedical Solutions, Point-of-Sale, Mation Solutions, etc.
Tools		tion, API/DLL for extended T. option
Part Number	SFPAxxxxQvB0xss-t-dd-2r3-STD	SFSAxxxxQvBRxss-t-dd-2r6-STD
	 ATA 133 compliant Sophisticated Wear Leveling & Bad Block Management S.M.A.R.T. support with extended command set Intelligent Power Fail Protection & Recovery Security Features available 	 Ideal Replacement for 2.5" SATA HDDs Low Power Consumption No Noise or Temperature Issues Long Useful Life S.M.A.R.T. support Advanced Wear Leveling & Block Management Power Fail Protection Security Features available



MSATA SSD, SLIM SATA & CFASTTM

SLIM SATA SSD (MO-297A) MSATA SSD (MO-300B)

The X-200 Series Slim SATA & mSATA embedded SSDs standard is ratified by JEDEC under specification number M0-297A & M0-300B. These products are designed as a cost efficient Solid State Drive alternative to larger size SSDs in embedded applications. The Slim SATA X-2005 includes the same standard 22-pin SATA connector as the 2.5" drives. This allows system designers to leverage standard SATA cabling or host connections for their application.



CFAST[™] CARD - THE NEXT COMPACTFLASH[™] GENERATION



The CFast[™] card combines the CompactFlash[™] (CF) card form factor with a Serial ATA (SATA) interface. With this merging of two industry standards, the CFast[™] card specification was created to replace existing hard drives and CompactFlash[™] in applications requiring small form factors, long life endurance and the ability to withstand shock, vibration, extreme temperatures (-40°C to +85°C), high altitude and other aggressive environments. Swissbit's CFast[™] is designed to provide rugged storage for embedded and industrial systems. In these markets, performance, data and system reliability, system downtime, power fail robustness and flexibility are important design considerations.

The CFast™ card operates with 3.3 Volt low power source and supports three SATA power management states: Active, Partial and Slumber. This standard is a perfect choice for both, boot devices and removable applications, where low to medium storage densities (up to 64GB) are required and the physical size of conventional mechanical or solid state hard drives are impractical. Certainly, the Swissbit CFast™ card comes with full engineering and customizing support and life time monitoring features, like S.M.A.R.T. with our intelligent flash managing algorithms and error correction, the latest F-200 Series will continue to provide the same reliability parameters using 32nm Flash instead of 4xnm technology while offering competitive pricing and SLC memory densities.

	*	1			£		
X-200M	•	0	•	•	0	0	٠
X-2005	•	0	•	•	0	0	٥
F-100	•	•	•	•	0	0	٥
F-200	•	•	•	•	٥		

default implemented; •¹ inherently protected by molding process; • on request; on available;

			A swissbit 4GB Industrial CFast ^{The} Card	Swissbit* 64GB Industrial CFest ^{tie} Card	
	mSATA SSD MO-300B	SLIM SATA SSD MO-297A	CFAST [™] CARD	CFAST [™] CARD	
Series	X-200m	X-200s	F-100	F-200	
Interface Compliance	sATA II - 3 Gbit/s ATA7	sATA II – 3 Gbit/s ATA7	CFast™ – sATA II – 3 Gbit/s ATA7	CFast™ – sATA II – 3 Gbit/s ATA8/ATA7 compliant	
Connector	52 pin PCI Express (PCIe) mini	15 + 7pin Serial ATA	CFast™ Type I	CFast™ Type I	
Physical Form	50.8 x 29.85 x 3.3 mm (MO-300B)	54 x 39 x 4.00 mm (M0-297A)	36.4 X 42.8 X 3.6 mm	36.4 X 42.8 X 3.6 mm	
Flash Type	SLC	SLC	SLC	SLC	
Density	2 GB - 32 GB	2 GB - 32 GB	2 GB - 32 GB	2 GB - 64 GB	
Operating Temperature	Commercial: 0°C to +70°C Industrial: -40°C to +85°C	Commercial: 0°C to +70°C Industrial: -40°C to +85°C	Commercial: 0°C to +70°C Industrial: -40°C to +85°C	Commercial: 0°C to +70°C Industrial: -40°C to +85°C	
Storage Temperature	-50°C to +100°C	-50°C to +100°C	-50°C to +100°C	-50°C to +100°C	
Shock	1 500 G	1 500 G	1 500 G	1 500 G	
Vibration	20 G	20 G	20 G	20 G	
Humidity	85 % RH 85°C, 1 000 hrs	85 % RH 85°C, 1 000 hrs	85% RH 85°C, 1 000 hrs	85 % RH 85°C, 1 000 hrs	
Data Transfer Mode	up to PIO4, MDMA2, UDMA6	up to PIO4, MDMA2, UDMA6	up to PIO4, MDMA2, UDMA6	up to PIO4, MDMA2, UDMA6	
Performance	Burst Rate up to 300 MB/s Read Seq. up to 120 MB/s Write Seq. up to 95 MB/s	Burst Rate up to 300 MB/s Read Seq. up to 120 MB/s Write Seq. up to 95 MB/s	Burst Rate up to 300 MB/s Read Seq. up to 120 MB/s Write Seq. up to 95 MB/s	Burst Rateup to 300 MB/sRead Seq.up to 130 MB/sWrite Seq.up to 100 MB/sWrite Rand. 4kup to 600 IOPS	
Voltage	3.3 V +/- 5 %	5 V +/- 10 %	3.3 V +/- 5 %	3.3 V +/- 5 %	
Power Consumption	typ 300 mA, max 490 mA Idle 180 mA	typ 260 mA, max 320 mA Idle 140 mA	typ 300 mA, max 420 mA Idle 180 mA	typ 140 mA, max 250 mA Idle 80 mA, Sleep 8 mA	
Marking		ımber, Lot Code, Mfg. Date	Mfg. Da	CE, Part Number, Lot Code, te, RoHS	
Target Application	Industrial Embedded	Systems, Medical Solutions, Poin	t-of-Sale, Gaming Industry, Auto	mation Solutions, etc.	
Tools		tion, API/DLL for extended . optional	Windows / Linux Application, API/DLL for extended S.M.A.R.T. optional Evaluation kit with 2.5" sATA adapter board available	Windows / Linux Application, API/DLL for extended S.M.A.R.T. optional Evaluation kit with 2.5" sATA adapter board available Security & SBZonePro- tection option	
Part Number	SFSAxxxxUvBRxss-t-dd-2r6-STD	SFSAxxxxVvBRxss-t-dd-2r6-STD	SFCAxxxxHvBRxss-t-dd-2r6-STD	SFCAxxxxHvBVxss-t-dd-2r6-STD	
	 Ideal Replacement for 2.5" S Cost efficient SATA SSD modu sATA II Interface compliant Advanced Wear Leveling & B S.M.A.R.T. support Power Fail Protection 	le	 Alternative for expensive sATA SSD Replacement for CFC by sATA Chipset sATA II Interface compliant Advanced Wear Leveling & Block Management S.M.A.R.T. support Power Fail Protection 	 Power modes (slumber, sleep) Low Power removable or fix SATA SSD High IOPS performance for 4k write (no DRAM) Sophisticated Wear Leveling & Bad Block Management Intelligent Power Fail Protection & Recovery S.M.A.R.T. support with extended command set Trim support SBZoneProtection option Fast Erase option 	





UNIVERSAL SERIAL BUS - USB FLASH DRIVE / MODULE

The Universal Serial Bus (USB) interface is very well established and has completely overtaken other forms of serial or parallel interfaces for computer peripherals and memory storage devices. Advantages of USB are its flexibility, reasonably fast sequential data transfer rate and its ability to obtain power through the connector. Almost every computer or embedded system supports devices with the standard USB socket and several internal on-board terminal headers. Swissbit is offering both in different form factors and in commercial and industrial operating temperature ranges. State of the art NAND Flash handling algorithms, stringent component selection, product change control and a 100% implemented final system test at full temperature range (-40° to +85°C) qualify Swissbit's USB Flash Drive (UFDs) not only for commercial but also and especially for embedded and industrial markets. Swissbit's U-110 Series (USB Flash Module) offers a no compromise flash based storage solution for:

- Embedded PCs that need a rugged reliable storage solution
- Servers with backup or recovery functionality
- General industrial computers with needs for easy to use boot mediums

All Swissbit USB solutions combine security features and Life Time Monitoring tools for product life control.









USB FLASH MODULE USB FLASH DRIVE

USB FLASH DRIVE

Series	U-110	unitedCONTRAST II	miniTWIST/CAP II
Interface Compliance	I	USB 2.0 high speed, USB 1.1 compliar	nt
Connector	Standard: 2.54 mm – 10 Pin Low Profile: 2.00 mm – 10 Pin	USB 2.0 A-Plug	USB 2.0 A-Plug
Physical Form	36.8mm x 26.65 mm x 2.4 mm	68.0 mm x 18.0 mm x 8.0 mm	55.0 mm x 16.0 mm x 7.0-8.0 mm
Flash Type	SLC	SLC	SLC
Density	1 GB to 8 GB	512 MB to 8 GB	128 MB to 4 GB
Operating Temperature	Commercial: o°C to +70°C Industrial: -40 to +85°C	Commercial: o°C to +70°C Industrial: -40°C to +85°C	Commercial: 0°C to +70°C
Storage Temperature	-50°C to +100°C	-50°C to +100°C	-50°C to +100°C
Shock	50 G	50 G	50 G
Vibration	15 G	15 G	15 G
Humidity	85 % RH 85°C, 500 hrs	85 % RH 85°C, 500 hrs	85 % RH 85°C, 500 hrs
Data Transfer Mode	full / high speed	full / high speed	full / high speed
Performance	480 Mbit/s USB 2.0 high speed Read Seq. up to 32 MB/s Write Seq. up to 23 MB/s	480 Mbit/s USB 2.0 high speed Read Seq. up to 32 MB/s Write Seq. up to 23 MB/s	480 Mbit/s USB 2.0 high speed Read Seq. up to 18 MB/s Write Seq. up to 12 MB/s
Voltage	5 V +/-10 %	5 V +/- 10 %	5 V +/- 10 %
Power Consumption	Full Speed typ 90 mA High Speed typ 100 mA	Full Speed typ 90 mA High Speed typ 100 mA	Full Speed typ 80 mA High Speed typ 100 mA
Marking	WEEE, Swissbit, Density, CE, FCC, Part Number, Lot Code	WEEE, Swissbit, Density	WEEE, Swissbit
Target Application	Industrial Embedded	Systems, Medical Solutions, Point-of- Automation Solutions, etc.	Sale, Gaming Industry,
Tools		Windows / Linux Application	
Part Number	SFUIxxxxJvBPxss-t-dd-2r1-STD - 2.54 mm SFUIxxxxKvBPxss-t-dd-2r1-STD - 2.00mm	SFU2xxxxEvBPxss-t-dd-1r1-STD	SFU2xxxxDvBP1ss-t-dd-1r1-STD
	 Bootable USB Drive Compliant with USB Specification 2.0 high speed Support latest 0S as Fixed Drive Connector Pitch Variations Robust Design and Shock Vibration Resistant 	 Approved USB Host Solution Hot Pluggable / Plug & Play Optimized Wear Leveling Custom Marking Option Security Features Password Manager available 	 Low Power Consumption Small Form Factor Optimized Wear Leveling Rotating Clip or Cap Option Password Manager available



Swissbit commits to offering the highest quality, JEDEC standard and customized DRAM modules for industrial applications. As a DRAM module manufacturer, we use strategic dual sources of DRAM suppliers to offer our customers a reliable, long term supply of leading edge and legacy memory module products. Special focus is put into working with suppliers that offer extended availability of DRAM die revisions, avoiding frequent requalification efforts with our customers.

Swissbit's quality focus starts with sourcing the highest quality grade DRAMs and, where defined, with utilizing fully compliant JEDEC module raw cards either as in-house PCB design or from top quality design partners. For all modules the passives and other active components selected are of the highest available quality grade. Using Surface Mount Technology (SMT) and Chip-On-Board (COB) processes in production on fully certified facilities in Germany allows Swissbit to sustain a quality focus during the entire assembly process. Traceability is guaranteed through the complete manufacturing and testing flow. We ensure the highest quality level for our customers with world class application testing. Swissbit uses internally developed application software to test 100% of all modules under real world conditions with diverse pattern and stress methods and to cover the complete memory array including ECC components by constantly adapting to the latest memory controller features. For industrial temperature grade modules the application tests are performed at -40°C and 85°C T AMBIENT.

With a stringent internal product qualification, fast customer return processing and the dedication to be an always improving company, Swissbit constantly works on providing its customers the best DRAM modules available in the market at a competitive price. Swissbit is committed and able to design, manufacture and test customer-specific module solutions. With broad experience from COB technology, we can offer PCB design and layout services, development of individual test solutions, thermal simulations, DRAM component sourcing, controlled manufacturing and special coating options.

With our Swissbit DRAM modules you can keep the total system cost at a minimum.



UNBUFFERED DIMM PRODUCTS



LONG UDIMM / WITH AND WITHOUT ECC

	Data Rate / CL	Density	Org	Height	Voltage	Pins	Partnumber	Package
DDR3-UDIMM	1333 / CL9	1 GB - 8 GB	x64	1.18" (29.97 mm)	1.50 V	240	SGUxxx64xxxxxxx-ssR	BGA
DDR3-UDIMM ECC	1333 / CL9	1 GB - 8 GB	X72	1.18" (29.97 mm)	1.50 V	240	SGUxxx72xxxxxx-ssR	BGA
DDR2-UDIMM	800 / CL6	512 MB - 2 GB	x64	1.18" (29.97 mm)	1.80 V	240	SEUxxx64xxxxxxx-ssR	BGA
DDR2-UDIMM ECC	800 / CL6	1 GB - 2 GB	X72	1.18" (29.97 mm)	1.80 V	240	SEUxxx72xxxxxx-ssR	BGA
DDR1-UDIMM	400 / CL3	512 MB - 1 GB	x64	1.25" (31.75 mm)	2.50 V	184	SDUxxx64xxxxxxx-ssR	TSOP
DDR1-UDIMM LP	400 / CL3	512 MB - 1 GB	x64	1.00" (25.40 mm)	2.50 V	184	SDUxxx64xxxxxxx-ssR	СОВ
DDR1-UDIMM ECC	400 / CL3	512 MB - 1 GB	X72	1.25" (31.75 mm)	2.50 V	184	SDUxxx72xxxxxx-ssR	TSOP
DDR1-UDIMM ECC LP	400 / CL3	512 MB - 1 GB	X72	1.00" (25.40 mm)	2.50 V	184	SDUxxx72xxxxxx-ssR	СОВ





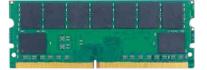


SO-DIMM / WITH AND WITHOUT ECC / RUGGED XR-DIMM

	Data Rate / CL	Density	Org	Height	Voltage	Pins	Partnumber	Package
DDR3-SODIMM	1333 / CL9 *)	1 GB - 8 GB	x64	1.18" (29.97 mm)	1.50 V *)	204	SGNxxx64xxxxxx-ssRT	BGA
DDR3-SO-UDIMM	1333 / CL9 *)	1 GB - 8 GB	X72	1.18" (29.97 mm)	1.50 V *)	204	SGNxxx72xxxxxx-ssRT	BGA
DDR3-XR-DIMM TM	1333 / CL9	1 GB - 4 GB	X72	38 mm x 67.5 mm	1.50 V *)	240	SGVxxx72xxxxxx-ssRT	BGA
DDR2-SODIMM	800 / CL6	512 MB - 4 GB	x64	1.18" (29.97 mm)	1.80 V	200	SENxxx64xxxxxxx-ssR	BGA
DDR2-SODIMM LP	800 / CL6	512 MB - 2 GB	x64	0.94" / 1.18"	1.80 V	200	SENxxx64xxxxxx-ssR	СОВ
DDR1-SODIMM	400 / CL3	256 MB - 1 GB	x64	1.25" (31.75 mm)	2.50 V	200	SDNxxx64xxxxxxx-ssR	BGA
DDR1-SODIMM LP	400 / CL3	256 MB - 2 GB	x64	1.00" (25.40 mm)	2.50 V	200	SDNxxx64xxxxxxx-ssR	СОВ
DDR1-SODIMM ECC	400 / CL3	256 MB - 1 GB	X72	1.00" (25.40 mm)	2.50 V	200	SDNxxx72xxxxxx-ssR	СОВ
SDR-SODIMM	133 / CL3	128 MB - 1 GB	x64	1.00" (25.40 mm)	3.30 V	144	SSNxxx64xxxxxxx-ssR	СОВ
SDR-SODIMM ECC	133 / CL3	128 MB - 1 GB	X72	1.00" (25.40 mm)	3.30 V	144	SSNxxx72xxxxxx-ssR	СОВ

*) DDR3-1600 CL11 and / or DDR3L (1.35V) on request





MINI-UDIMM / MICRODIMM / 100PIN-DIMM

	Data Rate / CL	Density	Org	Height	Voltage	Pins	Partnumber	Package
DDR3-MiniUDIMM	1333 / CL9	1 GB - 4 GB	X72	1.18" / 0.74"	1.50 V	244	SGLxxx72xxxxxx-ssRT	BGA
DDR2-MicroDIMM	667 / CL5	1 GB	x64	1.18" (29.97 mm)	1.80 V	214	SEMxxx64xxxxxxx-ssR	BGA
DDR1-100PIN_DIMM	333 / CL2.5	128 MB - 512 MB	X72	1.00" (25.40mm)	2.50 V	100	SDUxxx32xxxxxxx-ssR	TSOP

made in germany

RUGGEDIZED DIMMS





Designers of rugged platforms face a difficult decision when planning their memory layout. Either they use memory components directly soldered to the system board, the most rugged but also expensive and inflexible solution, or they take standard SO-DIMMs and try to ruggedize them by using straps or glue in order to hold them in their socket.

Swissbit in cooperation with the SFF-SIG consortium (Small Form Factor – Special Interest Group) has developed a rugged module called XR-DIMM[™], the abbreviation XR standing for eXtreme Rugged.

Using special mezzanine connectors and mounting holes to attach the module to the system board creates a true rugged system with the easy integration and flexibility of DIMM solutions and the shock and vibration immunity of implementations with DRAMs soldered to the board. The XR-DIMM closely follows the DDR3 72bit SODIMM standard and makes design in as easy as using a JEDEC module, unburdening the system designer of memory channel layout.

With multiple module densities the system integrator can create different memory populations with one system platform, avoiding multiple system board SKUs and taking benefit in perfectly tested modules with a just in time purchase option.



	Memory down SODIMM with fixture		XR-DIMM
DESIGN IN / LAYOUT	Difficult	Easy	Easy
FLEXIBILITY OF MEMORY POPULATION	Difficult	Easy	Easy
TESTABILITY AFTER SOLDERING	Medium	Easy	Easy
UPGRADE / REPAIR	Difficult	Easy	Easy
REQUIRED BOARD SPACE	Small to Medium	Medium to Small	Medium to Small
STACKABLE SOLUTION	No	Yes	Yes
PROTECTION AGAINST SHOCK	Good	Medium (with glue / strap)	Good
PROTECTION AGAINST VIBRATION	Good	Bad	Good
PRIZE	Low to Medium	Low	Medium

REGISTERED DIMM PRODUCTS



LONG RDIMM / STANDARD HEIGHT / WITH ECC AND C/A PARITY

	Data Rate / CL	Density	Org	Height	Voltage	Pins	Partnumber	Package
DDR3-RDIMM	1333 / CL9	1 GB - 8 GB	X72	1.18" (29.97 mm)	1.50 V	240	SGPxxx72xxxxxx-ssR	BGA
ECC+PARITY			A12	1.10 (29.9) 1111	1.90 V	240	501700127000000 551	bux
DDR2-RDIMM	0001616				- 0 - V		(FD	DCA
ECC+PARITY	800 / CL6	1 GB - 4 GB	X72	1.18" (29.97 mm)	1.80 V	240	SEPxxx72xxxxxx-ssR	BGA
DDR1-RDIMM					1/		(DD D	TODIOD
ECC	400 / CL3	512 MB - 2 GB	X72	1.20" (30.48 mm)	2.50 V	184	SDRxxx72xxxxxx-ssR	TSOP / BGA
SDR-RDIMM					1/		66D	TCOD
ECC	133 / CL3	256 MB - 512 MB	X72	1.20" (30.48 mm)	3.30 V	168	SSRxxx72xxxxxx-ssR	TSOP



LOW PROFILE LONG RDIMM, UDIMM / WITH ECC

	Data Rate / CL	Density	Org	Height	Voltage	Pins	Partnumber	Package
DDR3-RDIMM ECC+PARITY	1333 / CL9	2 GB - 8 GB	X72	0.70" (17.78 mm)	1.50 V	240	SGPxxx72xxxxxx-ssR	BGA
DDR3-UDIMM ECC	1333 / CL9	2 GB - 4 GB	X72	0.70" (17.78 mm)	1.50 V	240	SGUxxx72xxxxxx-ssR	BGA
DDR2-RDIMM ECC+PARITY	800 / CL6	1 GB - 2 GB	X72	0.72" (18.29 mm)	1.80 V	240	SEPxxx72xxxxxx-ssR	BGA





VLP MINIRDIMM WITH ECC, REGISTERED SO-RDIMM WITH ECC

	Data Rate / CL	Density	Org	Height	Voltage	Pins	Partnumber	Package
DDR2-MiniRDIMM	667 / CL5	1 GB	X72	0.72" (18.29 mm)	1.80 V	244	SEHxxx72xxxxxx-ssR	BGA
DDR2-SO-RDIMM	667 / CL5	1 GB - 2 GB	X72	1.18" (29.97 mm)	1.80 V	200	SEGxxx72xxxxxx-ssR	BGA



CHIP ON BOARD (COB)



Chip-On-board (COB) technology involves mounting DRAM or Flash semiconductor dies directly on a substrate and connect them by bond wires to the PCB without the need of packaged component. A coating of an Epoxy encapsulent (or Glob Top) is then applied that hermetically seals and protects the die and the wire bonded interconnections. The Glob Top also acts like a heat spreader between the dies and improves the heat emission together with the low thermal resistance between the die and the PCB.

A COB memory module as offered by Swissbit provides customers with the following advantages:

- The COB process allows DRAM modules with only 1.00" (25.4 mm) height and 3.0 mm thickness
- The thermal properties of Swissbit modules are superior to standard SMT modules. COB modules dissipate heat more efficiently and will run lower die junction temperatures in demanding convective cooling conditions.
- Swissbit COB modules and Flash products like the SD card are inherently ruggedized for shock and vibration due to the COB technology and the Glob Top encapsulation process.

SYSTEM IN PACKAGE (SIP)

System in Package (SiP) is the processing of sensitive bare dies or chips into robust finished modules or components.With 20 years of experience, Swissbit successfully uses advanced packaging technologies in order to achieve smallest form factors and to build Multi-Chip-Packages. With this microelectronic integration approach our products provide more functionality or highest memory densities inside one package, various functional blocks (RF, digital, sensors, security and memory) are combined, as well as passive components. Beginning with the wafer and bare die handling, Swissbit utilizes a flexible chip on board (COB) assembly and packaging line. Processes like SMT assembly, die bonding, Au and Al wire bonding, glob top dispensing, precise separation with laser technology, housing, labeling, laser marking etc. are very well established. Die stacking, especially for Flash and DRAM, is one of our expertise besides the integration of additional hardware features and an experienced team of testing and quality engineers. Our own Memory-In-Package line qualifies (but not limits) Swissbit as the development and production partner for any dedicated or customized memory-related product with challenging integration or reliability requirement. If you cannot achieve the special demands regarding space and performance using traditional components and processes, Swissbit offers feasibility studies, manages or supports your development project and produces prototypes, small and mid-size volumes (up to 50'000 pieces/ month). We will aid you from the time of inception of your project: from the design phase, prototyping, determining the circuit layout and material selection, to preparing the appropriate packaging for transport.

INDUSTRIAL TEMPERATURE RANGE



In addition to modules for commercial temperature range o°C to 70°C, Swissbit also offers products for an extended temperature range of o°C to 85°C T_{AMBIENT} as well as full industrial temperature range -40°C to 85°C T_{AMBIENT}. With intensive application testing of each individual module at low and high temperature, Swissbit ensures the highest quality and reliability of their products. CONFORMAL COATING



Industrial DRAM modules are often not operated in a clean air environment as compared to standard office or home conditions. A heavy industry environment with hot or humid air, aggressive chloride of sulfite loaded gas or dust can reduce the life span of a DRAM module by corroding the PCB lines or solder contacts. Swissbit offers a full module surface coating with a thin film of polyurethane which effectively protects against most hazardous environmental conditions. With this protection the endurance of the module is greatly improved, thus reducing maintenance periods and avoiding sudden breakdown of a system. This option is currently available for SODIMMs as well as for several Flash products.

HEAT SPREADER

The critical condition for DRAMs is a high die temperature, because it leads to loss of cell information. With die sizes continually shrinking the power dissipation is concentrated on only a few square millimeters. Adding a heat spreader to a module allows the hot spots to easier dissipate the temperature over a bigger surface. This heat spreader levels out the module heat dissipation, thus reducing the hot spot temperature and improving the module reliability. Swissbit offers heat spreader solutions for some of its industrial temperature grade SODIMMs.

MINIATURIZATION

One of Swissbit's main capabilities is miniaturization. This is not just limited to the design and production of small form factors but also provides e.g. DRAM test or flash handling algorithms which achieve highest reliability and life times by dealing with the power, temperature and space restrictions of small and smallest devices. Our portfolio reaches from ultra low profile DIMMs or highest integration wire-bonded modules to highly integrated uSD-Cards, Chip Card Inlays or custom Multi-Chip-Packages.



	B O 2 TO - I - M S - * - * 7 8 9 10 11 12 13 14 15
Swissbit	
Memory (1)	Design Option (15)
Memory Type (2)	Configuration (14)
F: Flash Products	PIN Mode (13)
	0: 1 nCE & R/nB
Product Type (3)	1: 2 nCE & R/nB
U2: USB 2.0 Drive	2: 4 nCE & R/nB
CA: CFast™	A: LGA 1 nCE & R/nB
CF: CompactFlash™	B: LGA 2 nCE & R/nB
UI: UFD internal / Module	C: LGA 4 nCE & R/nB
SD: SecureDigital card	S: TSOP 1 nCE & R/nB
MM: Multimedia card	T: TSOP 2 nCE & R/nB
PA: PATA/IDE	U: TSOP 4 nCE & R/nB
SA: SATA	E: COB 1 nCE
	F: COB 2 nCE
Density (4) 0016: 16 MByte 4096: 4 GByte	Flash Package Classification (12)
0032: 32 MByte 8192: 8 GByte	M: SLC SDP (single die package)
0064: 64 MByte 016G: 16 GByte	D: SLC DDP (dual die package)
0128: 128 MByte 032G: 32 GByte	Q: SLC DDF (dual die package)
0256: 256 MByte 064G: 64 GByte	N: SLC ODP (quad die package)
0512: 512 MByte 128G: 128 GByte	
1024: 1 GByte 256G: 256 Gbyte	G: MLC SDP (single die package)
2048: 2 GByte 512G: 512 Gbyte	L: MLC DDP (dual die package)
	H: MLC QDP (quad die package) O: MLC ODP (octal die package)
Product Dimension (5)	
H: CompactFlash™ / CFast™	
J: UFD Module 2.54 mm terminal header	I: Industrial Temp. (-40°C to + 85°C)
K: UFD Module 2.00 mm terminal header	E: Extended Temp. (-25°C to +85/90°C)
L: SD card	C: Commercial Temp. (0°C to + 70°C)
N: microSD card	
O: Multimedia card	Flash Supplier (10)
Q: SSD 2.5"	SA: Samsung
U: mSATA (MO-300B)	MT: Micron Technology
V: SLIM SATA (MO-297A)	HY: Hynix
Product Generation (6)	TO: Toshiba
Memory Organization (7)	Chips / Channels (9)
,,,,,,,,	
Technology (8)	

DRAM PART NUMBER DECODER

SGN	08G	72	G1	в	в	2	SA	- CC	*	R	т		
Swissbit Memory (1)	4	5		7	8	9	10	11	12	13		ermal Sensor / Spreader (14)	
Product Group (2)											RoHs/ L	ead Free (13)	
S: SDRAM SDR											Temperatu	re Rating (12)	
D: SDRAM DDR E: SDRAM DDR2 G: SDRAM DDR3 L: SDRAM DDR3L									C: (or blank) (0°C to +70°C) E: Ext. Temp.(0°C to +85°C) I: Ext. Temp.(-25°C to +85°C) W: Ind. Temp.(-40°C to +85°C)				
Module Type (3)												Speed (11)	
SDR U: 168 Pin UDIMM 3.3 V R: 168 Pin RDIMM 3.3 V N: 144 Pin SODIMM 3.3 V DDR U: 184 Pin UDIMM 2.5 V R: 184 Pin RDIMM 2.5 V N: 200 Pin SODIMM 2.5 V									DDR3	BA: CA: CC: DA:	DDR3-800 CL5 DDR3-1066 CL6 DDR3-1333 CL7 DDR3-1333 CL9 DDR3-1600 CL9 DDR3-1600 CL11	AB: DDR3-800 CL6 BB: DDR3-1066 CL7 CB: DDR3-1333 CL8 DB: DDR3-1600 CL10	
M: 172 Pin Micro-DIMM 2.5 V DDR2 U: 240 Pin UDIMM 1.8 V R: 240 Pin RDIMM 1.8 V, w/o F P: 240 Pin RDIMM 1.8 V, w/ Pa									DDR2	30: 25:	DDR2-400 CL3 DDR2-667 CL5 DDR2-800 CL6 DDR2-1066 CL7	37: DDR2-533 CL4 3A: DDR2-667 CL4 2A: DDR2-800 CL5	
 F: 240 Pin FBDIMM N: 200 Pin SODIMM 1.8 V G: 200 Pin SO-RDIMM 1.8 V H: 244 Pin Mini RDIMM 1.8 V, 1 	w/ Parity								DDR	70: 60:	DDR-200 CL2 DDR-266A CL2 DDR-333B CL2.5 DDR-400B CL3	75: DDR-266B CL2.5 7A: DDR-266A CL2 6A: DDR-333A CL2 5A: DDR-400A CL2.5	
M: 214 Pin MicroDIMM 1.8 V DDR3 U: 240 Pin UDIMM 1.5 V P: 240 Pin RDIMM 1.5 V									SDR		PC-100 CL3 PC-133 CL3	08: PC-100 CL2 70: PC-133 CL2	
N: 204 Pin SODIMM/SOUDIMM	1.5V				DRAM Manufacturer (10)				ufacturer (10)				
G: 204 Pin SO-RDIMM M: 214 Pin MicroDIMM 1.5 V L: 244 Pin MiniUDIMM V: 240 Pin XR-DIMM												MT: Micron Technology EP: Elpida GI: Gimonda SA: Samsung	
Data Depth (4)												HY: Hynix	
008: 64 MB 256: 2 GB 08G: 8	3 GB											WI: Winbond	
016: 128 MB 512: 4 GB				Module Ranks (9)									
032: 256 MB 01G: 8 GB 064: 512 MB 02G: 16 GB 128: 1 GB 04G: 32 GB												1: 1 Rank Module 2: 2 Rank Module	
Data Width (5)											DRA	M Revision (8)	
32: w/o Parity	2: w/o Parity										DRAM O	rganization (7)	
36: w/ Parity											A: x4	E: x8 TSOP Stack	
64: w/o ECC 72: w/ ECC											D: x4 TSOP Stack B: x8	C: x16 G: x4 BGA Stack	
Printed Circuit Board wi	th Revisio	on (6)											

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